

SS12F-SS110F

**SMAF Schottky Barrier Rectifier Diode 肖特基势垒整流二极管****■Features 特点**

Low forward voltage drop 低正向压降

High current capability 高电流能力

Surface mount device 表面贴装器件

Case 封装:SMAF



SMAF

**■Maximum Rating 最大额定值**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic 特性参数              | Symbol 符号           | SS12F          | SS13F | SS14F | SS15F | SS16F | SS18F | SS19F | SS110F | Unit 单位 |
|----------------------------------|---------------------|----------------|-------|-------|-------|-------|-------|-------|--------|---------|
| Peak Reverse Voltage 反向峰值电压      | V <sub>RRM</sub>    | 20             | 30    | 40    | 50    | 60    | 80    | 90    | 100    | V       |
| DC Reverse Voltage 直流反向电压        | V <sub>R</sub>      | 20             | 30    | 40    | 50    | 60    | 80    | 90    | 100    | V       |
| RMS Reverse Voltage 反向电压均方根值     | V <sub>R(RMS)</sub> | 14             | 21    | 28    | 35    | 42    | 56    | 63    | 70     | V       |
| Forward Rectified Current 正向整流电流 | I <sub>F</sub>      | 1              |       |       |       |       |       |       |        | A       |
| Peak Surge Current 峰值浪涌电流        | I <sub>FSM</sub>    | 30             |       |       |       |       |       |       |        | A       |
| Thermal Resistance J-A 结到环境热阻    | R <sub>θJA</sub>    | 50             |       |       |       |       |       |       |        | °C/W    |
| Junction Temperature 结温          | T <sub>J</sub>      | 150            |       |       |       |       |       |       |        | °C      |
| Storage Temperature 储藏温度         | T <sub>stg</sub>    | -65 to +150 °C |       |       |       |       |       |       |        | °C      |

**■Electrical Characteristics 电特性**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

| Characteristic 特性参数     | Symbol 符号                        | SS12F-<br>SS14F | SS15F-<br>SS16F | SS18F-<br>SS110F | Unit 单位 | Condition 条件                     |
|-------------------------|----------------------------------|-----------------|-----------------|------------------|---------|----------------------------------|
| Forward Voltage 正向电压    | V <sub>F</sub>                   | 0.55            | 0.70            | 0.85             | V       | I <sub>F</sub> =1A               |
| Reverse Current 反向电流    | I <sub>R</sub> (25°C)<br>(100°C) | 0.2<br>10       |                 |                  | mA      | V <sub>R</sub> =V <sub>RRM</sub> |
| Diode Capacitance 二极管电容 | C <sub>D</sub>                   | 110             |                 |                  | pF      | V <sub>R</sub> =4V,f=1MHz        |

## ■Typical Characteristic Curve 典型特性曲线

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

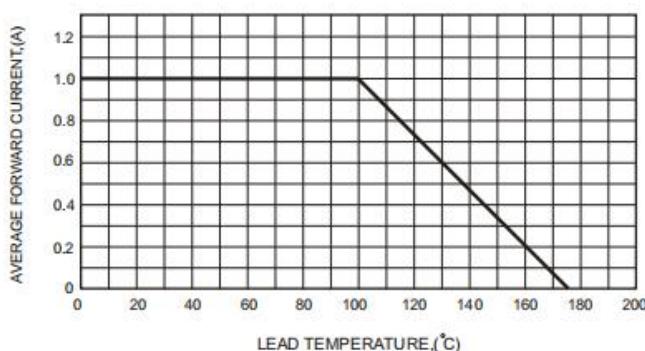


FIG.2-TYPICAL FORWARD CHARACTERISTICS

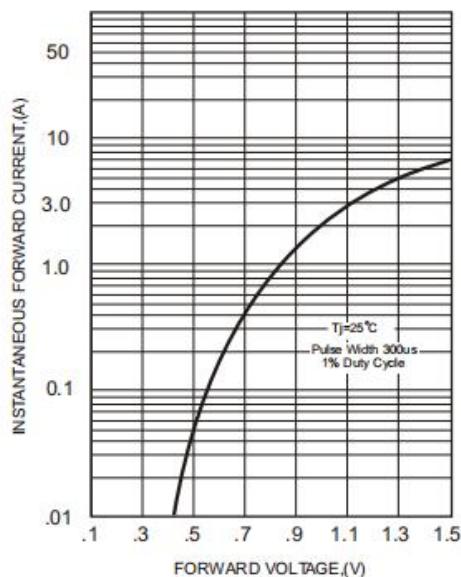


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

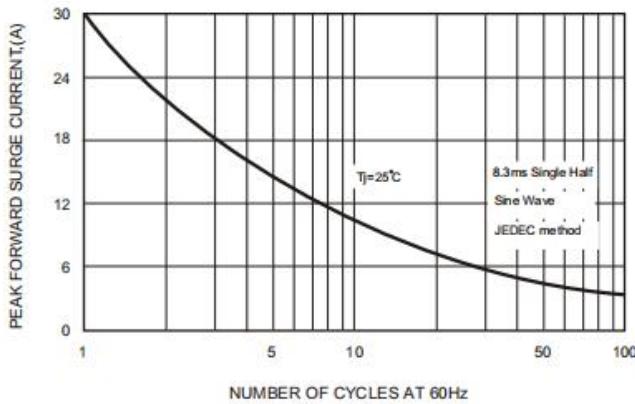


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

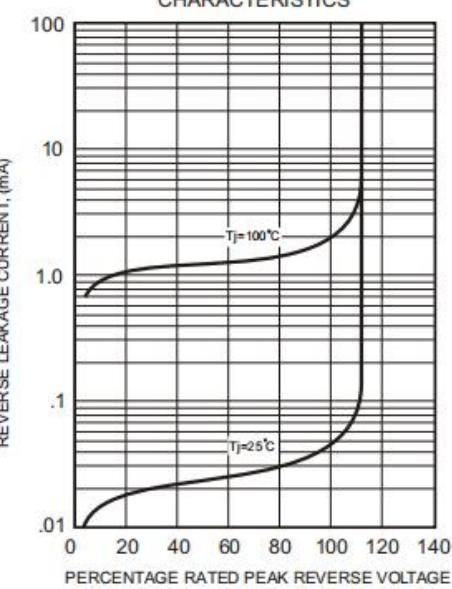
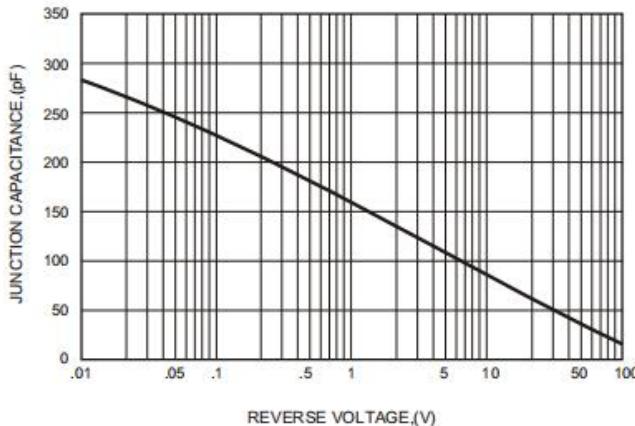


FIG.4-TYPICAL JUNCTION CAPACITANCE



■Dimension 外形封装尺寸

